NSN 5961-00-137-7555

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-137-7555 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 720.0 nonrepetitive peak reverse voltage and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 12.00 amperes average on-state current, 180 degrees conduction angle, average over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No